



**YEA SHIN TECHNOLOGY CO., LTD**

**FR2A THRU FR2M**

**FAST SWITCHING SURFACE MOUNT RECTIFIER**  
**VOLTAGE- 50 to 1000 Volts CURRENT - 2.0 Amperes**



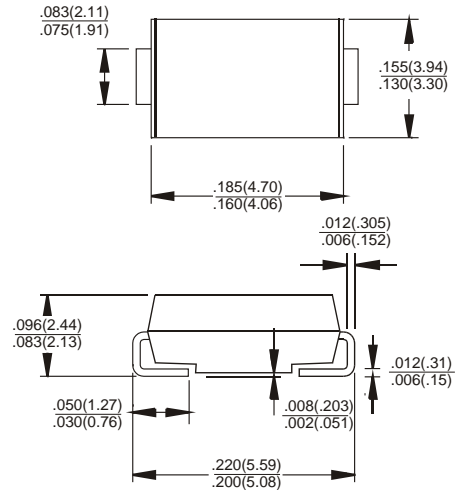
SMB/DO-214AA Unit:inch(mm)

**FEATURES**

- For surface mounted applications
- Low profile package
- Built-in strain relief
- Easy pick and place
- Fast Recovery times for high efficiency
- Plastic package has Underwriters laboratory Flammability Classification 94V-0
- Glass passivated junction
- High temperature soldering : 260 °C /10 seconds at terminals
- Pb free product at available : 99% Sn above meet RoHS environment substance directive request.

**MECHANICAL DATA**

- Case: JEDEC DO-214AA molded plastic
- Terminals: Solder plated, solderable per MIL-STD-750
- Method 2026
- Polarity: Indicated by cathode band
- Standard packaging: 12mm tape (EIA-481)



**MAXIMUM RATINGS AND ELECTRICAL CHARACTER**

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

	SYMBOLS	FR2A	FR2B	FR2D	FR2G	FR2J	FR2K	FR2M	UNIT
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current , at TL=90°C	I(AV)	2.0							A
Peak Forward Surge Current 8.3ms single half sinewave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>	50.0							A
Maximum Instantaneous Forward Voltage at 2.0A	V <sub>F</sub>	1.30							V
Maximum DC Reverse Current TA=25°C at Rated DC Blocking Voltage TA=125°C	I <sub>R</sub>	5.0 200							μA
Maximum Reverse Recovery Time(Note 1) T <sub>J</sub> =25°C	T <sub>RR</sub>	150				250	500		ns
Typical Junction Capacitance (Note 2)	C <sub>J</sub>	40.0							pF
Maximum Thermal Resistance(Note 3)	R <sub>θJL</sub>	20.0							°C / w
Operating and Storage Temperature Range	T <sub>J</sub> ,T <sub>STG</sub>	-55 to +150							°C

**NOTES :** 1. Reverse Recovery Test Conditions: IF=0.5A, IR=1.0A, Irr=0.25A  
 2. Measured at 1 MHz and applied Vr = 4.0 volts.  
 3. 8.0 mm2 ( .013mm thick ) land areas.

# DEVICE CHARACTERISTICS

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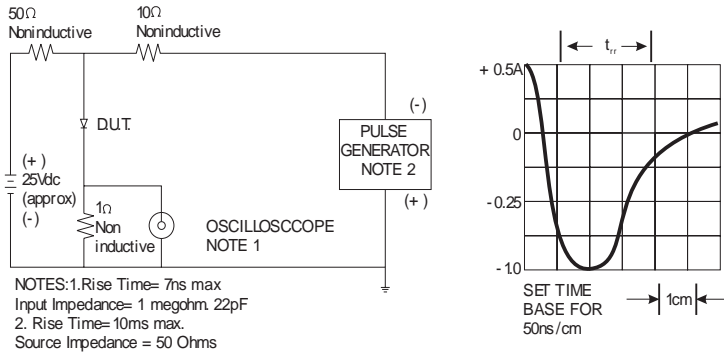


Fig.1-REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

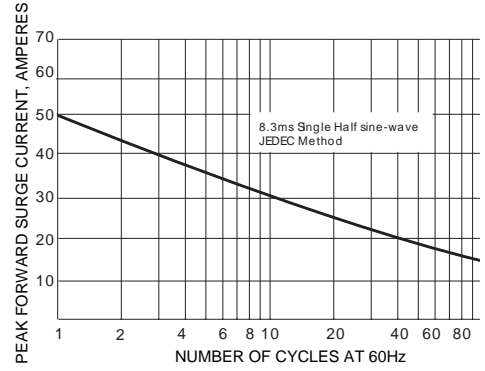


Fig.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

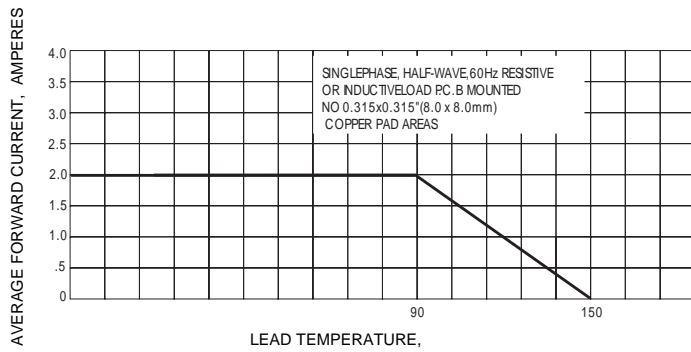


Fig.3-FORWARD CURRENT DERATING CURVE

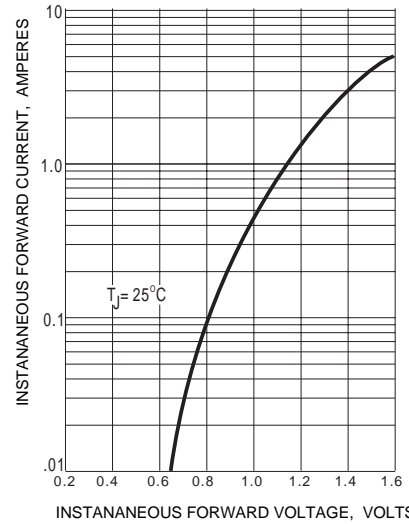


Fig.4-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

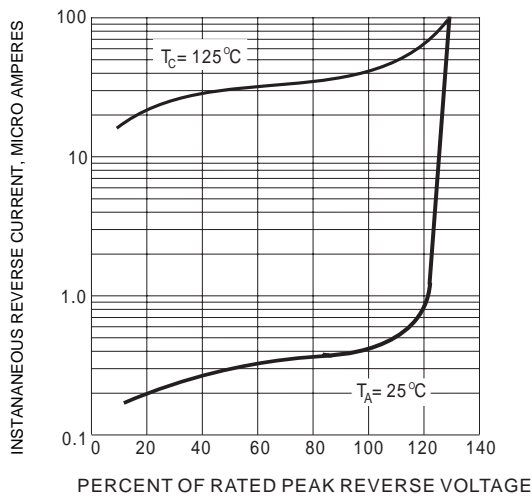


Fig.5-TYPICAL REVERSE CHARACTERISTICS

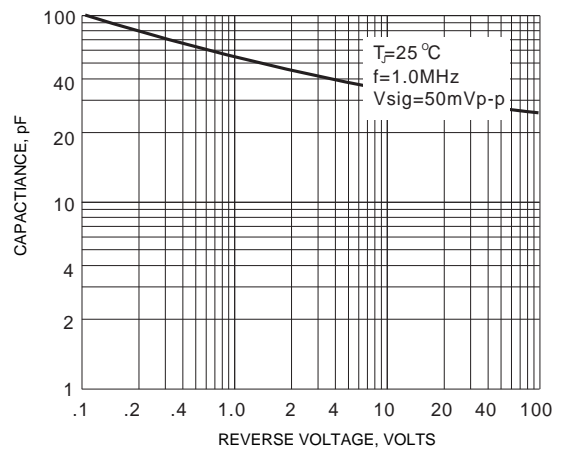


Fig.6-TYPICAL JUNCTION CAPACITANCE